

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	154768	(chip or IC or device or semiconductor) near9 resin	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:49
L2	19415	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:50
L3	377	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:51
L4	52	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (first near9 temperature)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:51
L5	32	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (first near9 temperature) and (second near9 temperature)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:51
L6	0	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (first near9 temperature) and (second near9 temperature) and (third near9 temperature)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:52
L7	0	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (first near9 temperature) and (second near9 temperature) and (transfer near mold\$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:53

EAST Search History

L8	0	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (first near9 temperature) and (second near9 temperature) and (transfer near mold\$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:54
L9	0	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (first near9 temperature) and (second near9 temperature) and (transfer near9 mold\$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 07:54
L10	9	(chip or IC or device or semiconductor) near9 resin and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (first near9 temperature) and (second near9 temperature) and molding and potting	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:23
L11	2593	((cure or curing) near9 resin) and ((bake or baking) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:24
L12	687	((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (thermoset\$4 near resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:26
L13	622	((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (thermoset\$4 near resin) and temperature	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:27
L14	2	((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (thermoset\$4 near resin) and temperature and (inspect near9 (device or chip or IC))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:27

EAST Search History

L15	2	((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (thermoset\$4 near resin) and temperature and ((inspect or inspecting) near9 (device or chip or IC))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:51
L16	2	((cure or curing) near9 resin) and ((bake or baking) near9 resin) and (thermoset\$4 near resin) and temperature and package and inspect	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:51
L17	3	((cure or curing) near9 resin) and ((bake or baking) near9-resin) and temperature and package and inspect	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:53
L18	7235	package and (thermoset\$4 near resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:53
L19	2758	package and (thermoset\$4 near resin) and ((cure or curing) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:54
L20	68	package and (thermoset\$4 near resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:54
L21	60	package and (thermoset\$4 near resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and temperature	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:54

EAST Search History

L22	37	package and (thermoset\$4 near resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and temperature and ((chip or IC or device or circuit) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:57
L23	14	package and (thermoset\$4 near resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and temperature and ((chip or IC or device or circuit) near9 resin) and inspect\$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 08:57
L24	12	package and (thermoset\$4 near resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and temperature and ((chip or IC or device or circuit) near9 resin) and ((inspect\$4 or monitor or test\$4) near9 (chip or IC or device or circuit))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:08
L25	149	((seal\$4 or encas\$4 or enclos\$4) near9 resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and ((chip or ic or circuit or device or semiconductor) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:10
L26	149	((seal\$4 or encas\$4 or enclos\$4) near9 resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and ((chip or IC or circuit or device or semiconductor) near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:11
L27	143	((seal\$4 or encas\$4 or enclos\$4) near9 resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and ((chip or IC or circuit or device or semiconductor) near9 resin) and temperature	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:11
L28	37	((seal\$4 or encas\$4 or enclos\$4) near9 resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and ((chip or IC or circuit or device or semiconductor) near9 resin) and temperature and (thermoset\$4 near resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:11

EAST Search History

L29	11	((seal\$4 or encas\$4 or enclos\$4) near9 resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and ((chip or IC or circuit or device or semiconductor) near9 resin) and temperature and (thermoset\$4 near resin) and molding and potting	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:29
L30	1	((seal\$4 or encas\$4 or enclos\$4) near9 resin) and ((cure or curing) near9 resin) and ((bake or baking) near9 resin) and ((chip or IC or circuit or device or semiconductor) near9 resin) and temperature and (thermoset\$4 near resin) and molding and potting and (inspect or monitor or test)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:12
L31	399485	((seal\$4 or enclose\$4 or encas\$4) near9 (IC or chip or device or circuit or semiconductor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:30
L32	54589	((seal\$4 or enclose\$4 or encas\$4) near9 (IC or chip or device or circuit or semiconductor)) same resin	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:31
L33	51	((seal\$4 or enclose\$4 or encas\$4) near9 (IC or chip or device or circuit or semiconductor)) same resin and ((curing or cure) near9 resin) and (bak\$4 near9 resin) and (thermoset\$4 near resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:32
L34	34	((seal\$4 or enclose\$4 or encas\$4) near9 (IC or chip or device or circuit or semiconductor)) same resin and ((curing or cure) near9 resin) and (bak\$4 near9 resin) and (thermoset\$4 near resin) and ((inspect\$4 or monitor\$4 or test\$4) same (IC or chip or device or circuit or semiconductor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/04/19 09:46
S1	15637	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/06/29 14:35

EAST Search History

S2	1967	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:21
S3	586	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:22
S4	341	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit and mold\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:22
S5	109	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit and mold\$4 and pot\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:22
S6	69	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit and mold\$4 and pot\$4 and seal\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:22
S7	53	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit and mold\$4 and pot\$4 and seal\$4 and lead	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:23
S8	43	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit and mold\$4 and pot\$4 and seal\$4 and lead and electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:23
S9	41	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit and mold\$4 and pot\$4 and seal\$4 and lead and electrode and solder	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:24
S10	0	resin near4 (bak\$4 or heat\$4 or anneal\$4) and cur\$4 and (temp\$4 or therm\$4) and (semiconductor or wafer or substrate) and thermoset and circuit and mold\$4 and pot\$4 and seal\$4 and lead and electrode and solder and (438/585.ccls.)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/08/31 08:23

EAST Search History

S11	4204	(semiconductor or substrate or wafer) and (thermoset\$4 near4 resin) and cur\$3 and bak\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:42
S12	33	(semiconductor or substrate or wafer) and (thermoset\$4 near4 resin) and cur\$3 and bak\$3 and seal\$3 and mold\$3 and pot\$3 and lead and temperature and chip	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:45
S13	21	(semiconductor or substrate or wafer) and (thermoset\$4 near4 resin) and cur\$3 and bak\$3 and seal\$3 and mold\$3 and pot\$3 and lead and temperature and (semiconductor near4 chip) and solder	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/29 14:46
S14	38625	(semiconductor or substrate or wafer) and (thermoset\$4 near4 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 11:52
S15	11389	(semiconductor or substrate or wafer) and (thermoset\$4 near4 resin) and (curing near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 11:53
S16	107	(semiconductor or substrate or wafer) and (bak\$4 near9 (thermoset\$4 near4 resin)) and (curing near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 11:54
S17	79	(semiconductor or substrate or wafer) and (bak\$4 near9 (thermoset\$4 near4 resin)) and (curing near9 resin) and temperature	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 11:54

EAST Search History

S18	2	(semiconductor or substrate or wafer) and (bak\$4 near9 (thermoset\$4 near4 resin)) and (curing near9 resin) and temperature and mold\$4 and pot\$4 and (aging near4 test\$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 12:05
S19	0	(semiconductor or substrate or wafer) and (bak\$4 near9 (thermoset\$4 near4 resin)) and (curing near9 resin) and temperature and mold\$4 and pot\$4 and (reliab\$4 near4 test\$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 12:05
S20	0	(semiconductor or substrate or wafer) and (bak\$4 near9 (thermoset\$4 near4 resin)) and (curing near9 resin) and temperature and mold\$4 and pot\$4 and inspect	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 12:06
S21	6	(semiconductor or substrate or wafer) and (bak\$4 near9 (thermoset\$4 near4 resin)) and (curing near9 resin) and temperature and mold\$4 and pot\$4 and test	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 12:16
S22	1	seal near9 (semiconductor or substrate or wafer) and (bak\$4 near9 (thermoset\$4 near4 resin)) and (curing near9 resin) and temperature and mold\$4 and pot\$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 12:17
S23	16	seal near9 (semiconductor or substrate or wafer) and (bak\$4 near9 resin) and (curing near9 resin) and temperature and mold\$4 and pot\$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/15 12:21
S25	81	(seal or enclose) near9 (semicondcutor or substrate or wafer) and (curing near9 resin) and (bak\$4 near9 resin) and temperature	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/29 08:31

EAST Search History

S26	14	(seal or enclose) near9 (semiconductor or substrate or wafer) and (curing near9 resin) and (bak\$4 near9 resin) and temperature and (transfer near4 mold) and (mount\$4 near9 (semiconductor or substrate or wafer))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/29 10:32
S27	17	seal near9 (semiconductor or circuit or device) and (bak\$4 near9 resin) and (curing near9 resin) and temperature and mold\$4 and pot\$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/22 09:51
S28	273	(resin near9 device) and ((curing or cure) near9 resin) and (bak\$4 near9 (temperature or heat)) and (semiconductor or wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/22 10:02
S29	3	(resin near9 device) and ((curing or cure) near9 resin) and (bak\$4 near9 (temperature or heat)) and (semiconductor or wafer or substrate) and (inspect near9 device)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/22 10:23
S30	0	(resin near9 device) and ((curing or cure) near9 resin) and (bak\$4 near9 (temperature or heat)) and (semiconductor or wafer or substrate) and (inspect near9 device) and ((mount or holder) near9 (device or circuit))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/22 10:04
S31	1	(resin near9 device) and ((curing or cure) near9 resin) and (bak\$4 near9 (temperature or heat)) and (semiconductor or wafer or substrate) and (inspect near9 device) and seal	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/22 10:24
S32	55	(seal\$4 near9 (resin near9 device)) and ((curing or cure) near9 resin) and (bak\$4 near9 (temperature or heat)) and (semiconductor or wafer or substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 10:46

EAST Search History

S33	1260	(cure or curing) near9 "thermoset resin"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 10:47
S34	220	(cure or curing) near9 "thermoset resin" near9 temperature	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 11:04
S35	1	(cure or curing) near9 "thermoset resin" near9 temperature and (bak\$4 near9 "thermoset resin")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 11:31
S36	4	(cure or curing) near9 "thermoset resin" near9 temperature and (bak\$4 near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 11:42
S37	80	(cure or curing) near9 "thermoset resin" near9 temperature and (semiconductor or substrate or wafer)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 11:43
S38	1	(cure or curing) near9 "thermoset resin" near9 temperature and (semiconductor or substrate or wafer) and (bak\$4 near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 11:45
S39	1	(cure or curing) near9 ("thermoset resin" or eopxy) near9 temperature and (semiconductor or substrate or wafer) and (bak\$4 near9 resin)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 11:46

EAST Search History

S40	1	(cure or curing) near9 ("thermoset resin" or eopxy) near9 temperature and (semiconductor or substrate or wafer) and (bak\$4 near9 (resin or epoxy))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 11:46
S41	186	seal\$4 near9 (semiconductor or substrate or wafer) and ((resin or epoxy) near9 (semiconductor or substrate or wafer)) and ((cure or curing) near9 (resin or epoxy)) and ((bake or baking) near9 (epoxy or resin)) and temperature	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/08 08:54
S42	21	seal\$4 near9 (semiconductor or substrate or wafer) and ((resin or epoxy) near9 (semiconductor or substrate or wafer)) and ((cure or curing) near9 (resin or epoxy)) and ((bake or baking) near9 (epoxy or resin)) and temperature and (thermal near9 (cure or curing))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/08 10:01
S43	19669	(transfer near4 mold)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/08 10:01